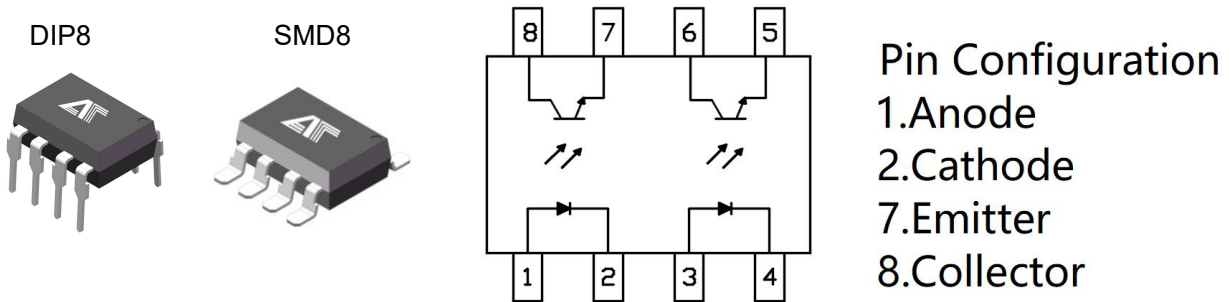


晶体管光耦 Photo Transistor

AT827-CuH-D

Product Data Sheet

AOTE DCC
RELEASE



◆ 封装逻辑原理图 Encapsulation logic schematic

AT827 光耦采用高效光电转换技术，结合先进封装工艺，提供输入输出间的可靠隔离，支持DIP8及SMD8两种封装形式，适配多样化场景需求。

The AT827 optocoupler adopts high-efficiency photoelectric conversion technology and advanced packaging processes, providing reliable input-output isolation. It supports two package types (DIP8 SMD8) to meet diverse application requirements.

◆ 产品特征 Product features

- 输入-输出隔离电压 $V_{ios}=5000V_{rms}$
Input output isolation voltage: $V_{ios}=5000 V_{rms}$
- 电流传输比 CTR: 80-600% Current Transfer Ratio: CTR: 80-600%
- 峰值击穿电压: $BV_{CEO}=80V$; Peak breakdown voltage: $BV_{CEO}=80V$
- 爬电距离 $>7.0mm$; Creepage distance $>7.0mm$;
- 输入-输出绝缘距离 $>0.4mm$; Input-Output insulation Thickness $>0.4mm$
- 防潮等级 class1; MSL class1
- 产品符合 ROHS、REACH 及 HF 等环保法规要求;
The products comply with ROHS, REACH and HF;

◆ 应用领域 Applications

- 工业控制 Industrial control
工业自动化设备 (PLC模块、传感器接口) Industrial automation equipment (PLC module, sensor interface)
测量仪器信号隔离 Measurement instrument signal isolation
- 电源系统 Power Systems:
智能电表、开关电源设计应用 Design and application of smart meters and switching power supplies
光伏逆变器、储能系统应用 Photovoltaic inverters, energy storage system applications
- 消费电子 Consumer Electronics:
家用电器主控电路 (空调、冰箱、热水器) Main control circuit for household appliances (air conditioning, refrigerator, water heater);
办公设备 (复印机) Office equipment (copier)



◆ 极限参数 Absolute Maximum Ratings (Ta =25°C)

参数 Parameter		符号 Symbol	额定值 Rating	单位 Unit
发射端 Input	正向电流 Forward Current	IF	50	mA
	反向电压 Reverse Voltage	VR	6	V
	功耗 Power Dissipation	PD	70	mW
	额定值降低因子(在 Ta = 100°C 以上) Power dissipationDerating factor (above Ta = 100°C)	PDD	2.0	mW/°C
	热阻(结-环境) Thermal Resistance Junction-Ambient	RthJ-A	325	°C/W
	热阻(结-壳) Thermal Resistance Junction-Case	RthJ-C	200	°C/W
接收端 Output	集电极功耗 Collector Power Dissipation	PC	150	mW
	集电极电流 Collector Current	IC	50	mA
	集电极-发射极电压 Collector-Emitter Voltage	VCEO	80	V
	发射极-集电极电压 Emitter-Collector Voltage	VECO	6	V
隔离电压 Isolation Voltage		Viso	5000	Vrms
工作温度 Operating Temperature		Topr	-55 ~+110	°C
存储温度 Storage Temperature		Tstg	-55 ~+125	°C
焊接温度 Soldering Temperature		Tsol	260	°C

◆ 推荐操作条件 Recommended Operating Conditions

参数 Parameter	符号 Symbol	最小值 Min	最大值 Max.	单位 Unit
正向电流 Forward Current	IF	5	15	mA
集电极-发射极电压 Collector-Emitter Voltage	VCEO	5	80	V
集电极电流 Collector Current	IC	5	35	mA

◆ 产品特性参数Product characteristic parameters (Ta =25°C)

参数 Parameter		符号 Symbol	条件 Condition	最小 Min	典型 Typ	最大 Max	单位 Unit
发射端 Input	正向电压 Forward Voltage	VF	IF=20mA	-	1.2	1.4	V
	反向电流 Reverse Current	IR	VR =4V	-	-	10	uA
	输入电容 Terminal Capacitance	Ct	V=0V, F =1KHz	-	30	250	pF
接收端 Output	集电极暗电流 Collector Dark Current	ICEO	VCE=20V, IF =0mA	-	-	100	nA
	集电极-发射极击穿电压 Collector-Emitter Breakdown Voltage	BVCEO	IC =0.1mA, IF =0mA	80	-	-	V
	发射极-集电极电压 Emitter-Collector Voltage	BVECO	IE =10uA, IF =0mA	6	-	-	V
传输特性 Transfer Characteristics	电流传输比 Current Transfer Ratio	CTR*	IF=1mA , VCE=5V	80	-	600	%
	集电极-发射极饱和压降 Collector-Emitter Saturation Voltage	VCE(sat)	IF=20mA, IC =1mA	-	0.1	0.2	V
	隔离电阻 Isolation Resistance	RISO	DC500V, 40 ~60%R.H.	5x10 ¹⁰	1x10 ¹¹	-	Ω
	隔离电容 Isolation capacitance	CISO	V=0,f=1MHz	-	0.6	1.0	pF
	截止频率 Cut-off Frequency	Fc	VCE=5V, IC =2mA, RL =100Ω,-3dB	-	80	-	kHz
	上升时间 Rise Time	Tr	VCE=2V, IC =2mA, RL =100Ω	-	3	18	μs
	下降时间 Fall Time	Tf	VCE=2V, IC =2mA, RL =100Ω	-	4	18	μs

注 电流传输比= $I_C/I_F \times 100\%$ 。

Note*: CTR= $I_C/I_F \times 100\%$ 。

◆ 电性特性曲线Electrical characteristic curve($T_a = 25^\circ\text{C}$)

Fig.1 Relative Current Transfer Ratio vs. Forward Current

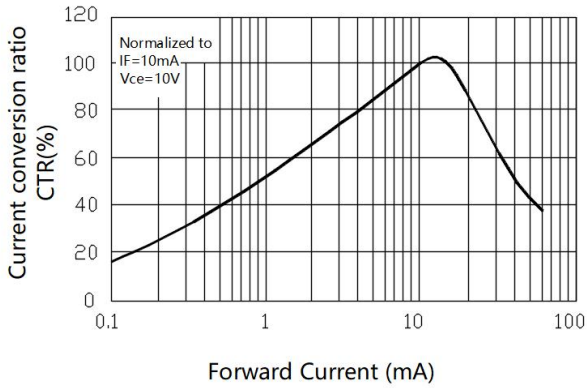


Fig.2 Forward Current vs Forward Voltage

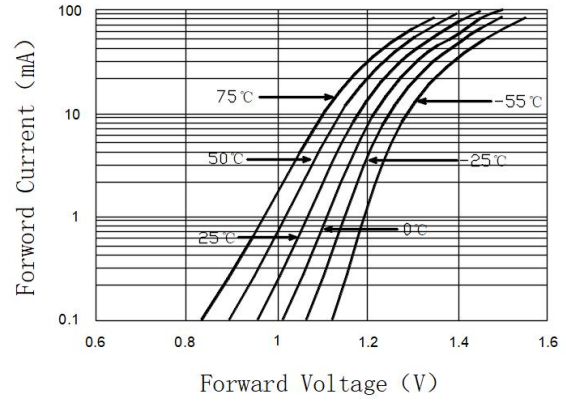


Fig.3 Collector Current vs. Collect-emitter voltage

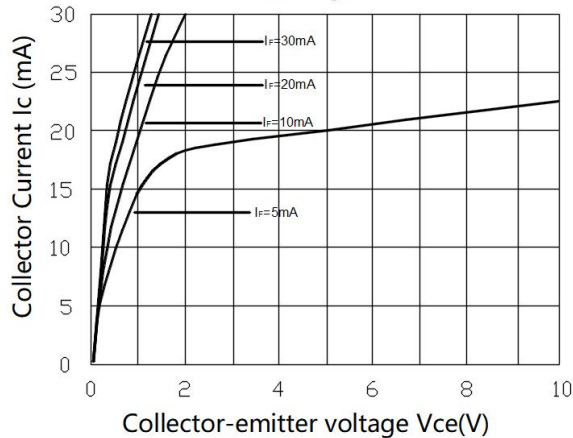


Fig.4 Relative Current Transte vs. Ambient Temperature

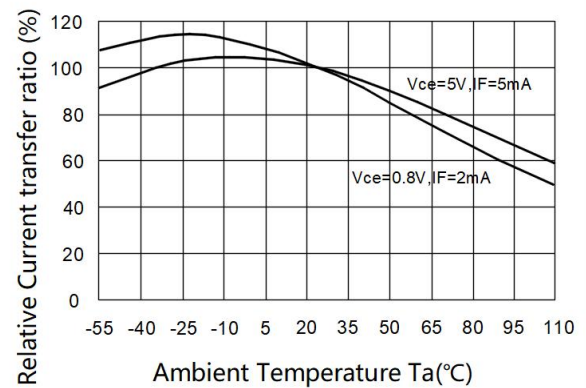


Fig.5 Collector-emitter Saturation Voltage vs. Ambient Temperature

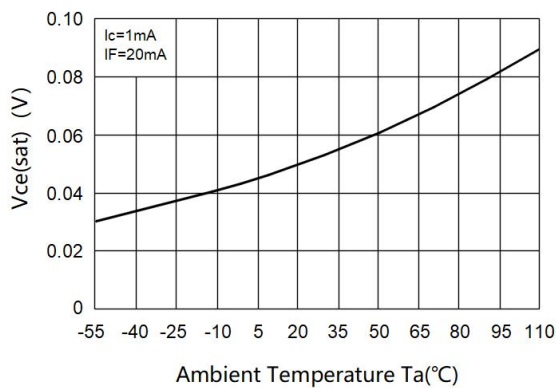


Fig.6 Collector Dark Current vs. Ambient Temperature

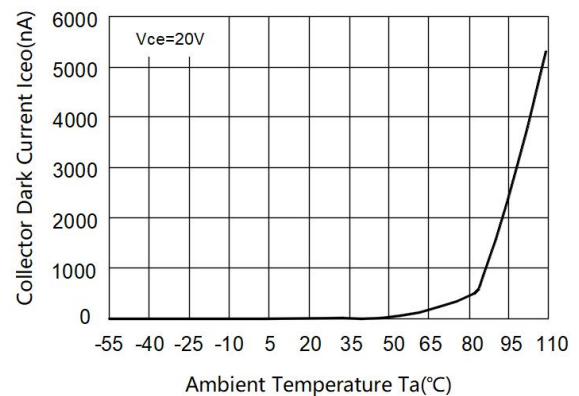


Fig.7 Response Time vs. LoadResistance

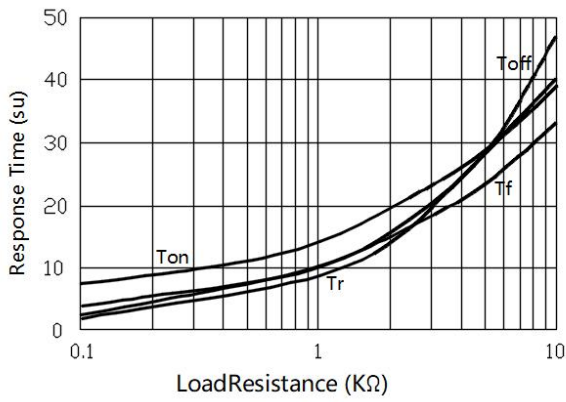


Fig.8 Frequency Response

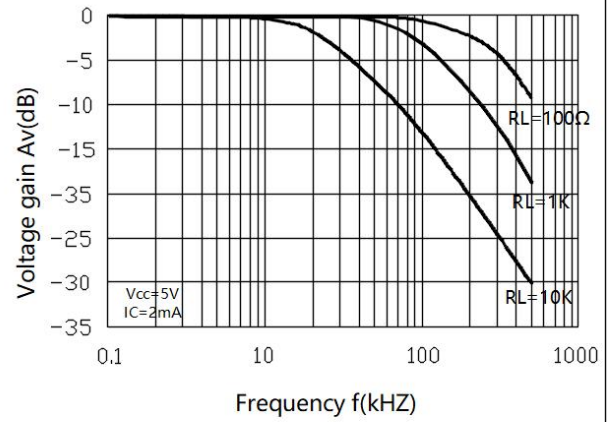


Fig.9 Collect-emitter Saturation Voltage vs. Forward Current

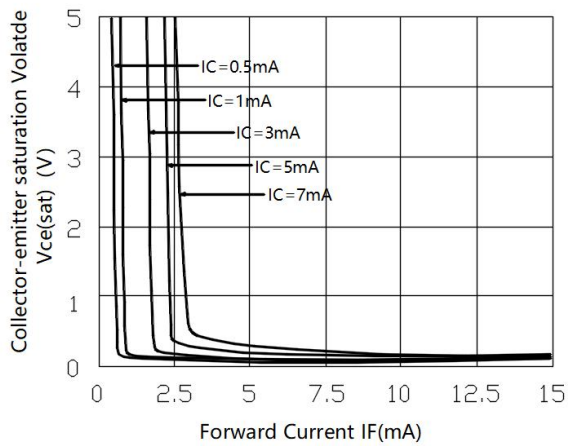
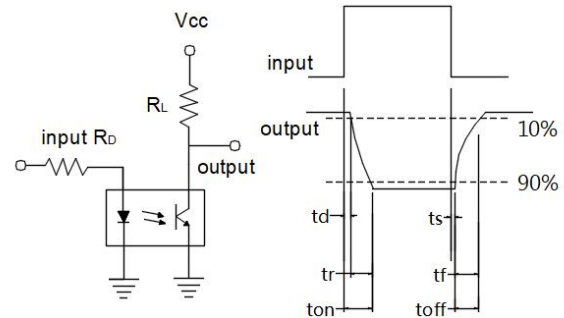
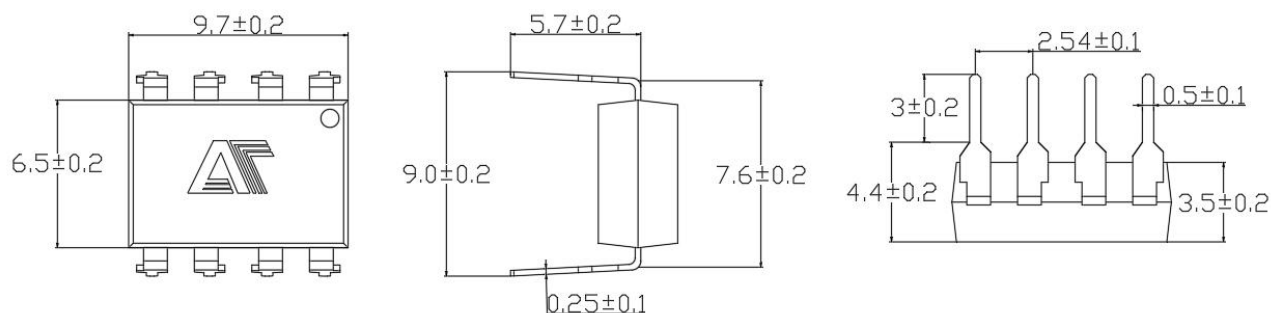


Fig.10 Switching Time Test Circuit & Waveforms

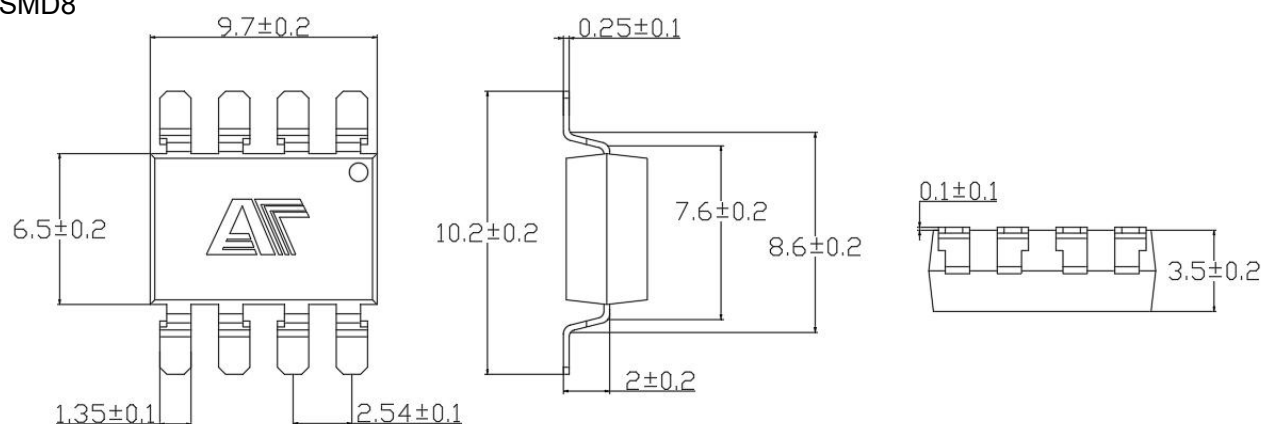


◆ 外形尺寸Overall dimension

DIP8

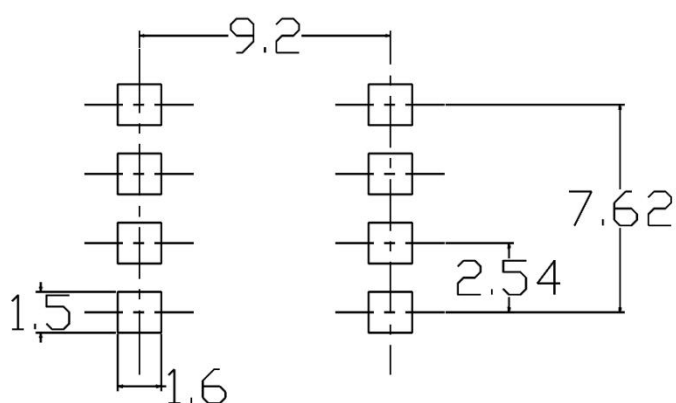


SMD8



推荐焊盘:

Recommended



单位: mm

◆ 产品型号命名规则 Order code

AT 827 - UN Y - W (V) (ZZ)

① ② ③ ④ ⑤ ⑥ ⑦

- ① 公司代码 Company Code (AT: 奥特 Aote)
- ② 产品系列 Product Series (827)
- ③ 框架类型 Lead Frame (Cu: 铜框架 Copper, Fe: 铁框架 Ferrum)
- ④ 树脂类型 Epoxy Type (H: 无卤 Halogen-free)
- ⑤ 封装形式 Package (D:DIP, S:SMD)
- ⑥ 器件工作温度范围 Device Operating Temperature Range (特殊范围需填或者空白 Special Range need to be filled in or left blank)
- ⑦ 内部补充代码 Internal Supplementary Code (数字或者空白 Number or None)

◆ 印字信息 Marking Information

- 印字中 “” 为奥特品牌LOGO
“” denotes LOGO
- 印字中 “Y” 代表年份; A(2018),B(2019),C(2020)
“Y” denotes YEAR: A(2018), B(2019), C(2020)
- 印字中 “WW” 代表周号
“WW” denotes Week' s number
- 印字中 “E” 代表内部代码
“E” denotes Internal code
- 印字中的 “H” 代表无卤
“H” denotes Halogen-free

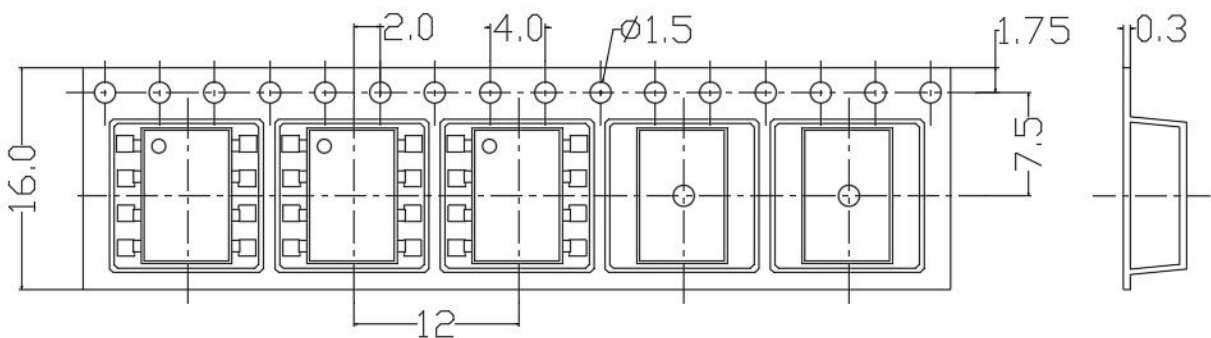
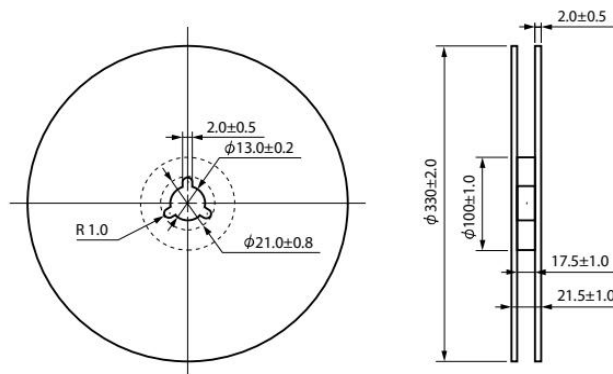


◆ 包装packing

封装形式	包装方式	盘数量	盒数量	箱数量	静电袋规格	盒规格	箱(双瓦楞)规格	备注
SMD8	卷盘 ($\phi 330$ mm蓝盘)	1000 只/盘	2 盘/盒	10 盒/箱	450*390*0.1mm	340*60*340 mm	620*360*365mm	首尾端空至少200mm
DIP8	管装 (500*12*11mm)	45 只/管	50 管/盒	10 盒/箱	不适用	525*128*56 mm	535*275*300mm	每管使用蓝白胶塞，方向须一致
Package Type	Packing Form	Quantity per Reel	Quantity per Box	Quantity per Carton	Antistatic Bag Specification	Box Specification	Carton Specification	Note
SMD8	Reel ($\phi 330$ mm Blue)	1000 pcs/reel	2 reels/box	10 boxes/ctn	450*390*0.1mm	340*60*340 mm	620*360*365mm	Leave at least 200mm of blank space at both ends
DIP8	Tube (500*12*11mm)	45 pcs/tube	50 tubes/box	10 boxes/ctn	NA	525*128*56 mm	535*275*300mm	Use blue and white rubber plugs for each tube in the same direction

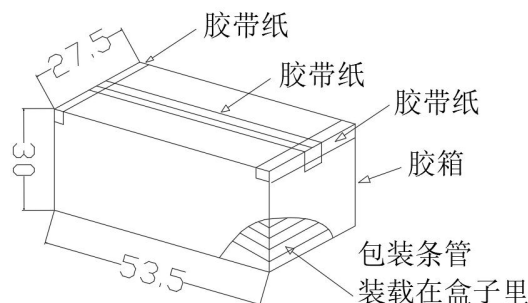
• 编带包装 Tape & Reel

- 1) 每卷数量: 2000 只;
Qty/reel: 2000 pcs;
- 2) 每箱数量: 40000 只;
Qty/ctn: 40000 pcs;
- 3) 内包装: 每盒 2 盘;
Inner packing: 2 reels/box;
- 4) 示意图 Schematic:



• 管条包装Tape&Tube

- 1) 每管数量: 45 只。
Qty/Tube : 45 pcs.
- 2) 每箱数量: 22500 只。
Qty/ctn: 22500 pcs.
- 3) 内包装: 每盒 50 管。
Inner packing: 50 Tube/box.
- 4) 示意图 Schematic

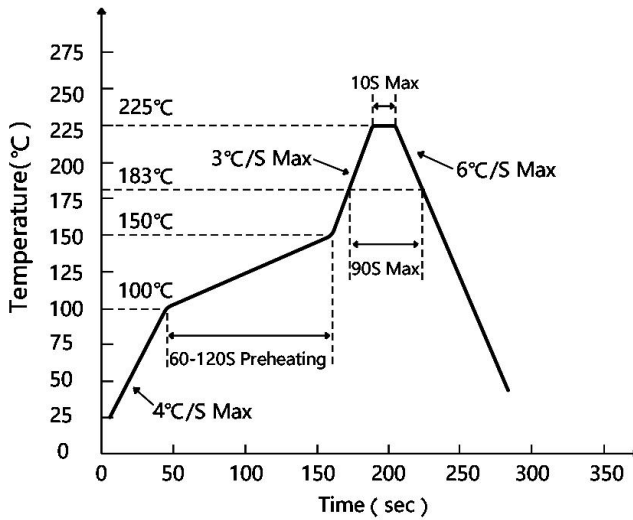


单位: mm

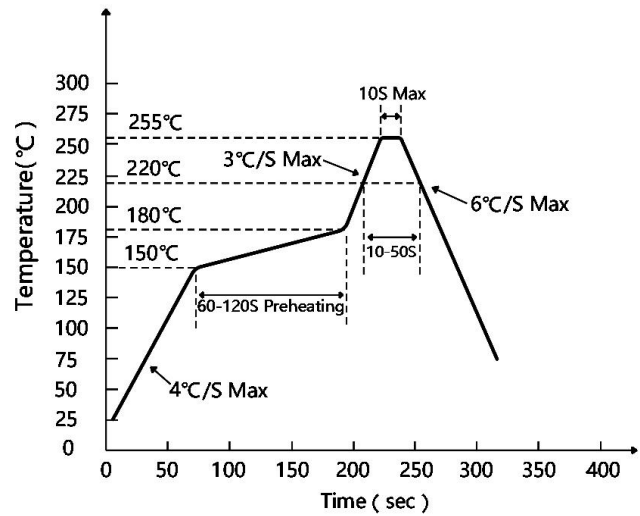
◆ 可靠性测试 Reliability Test Items And Conditions

实验项目 Test Items	参考标准 Reference	实验条件 Test Conditions	时间 Time	样品数 Quantity	判据 Criterion
可焊性 Solderability	JESD22-B102	Tsol= (245±5) °C, t=5s;	1 次1 times	22	0/22
耐焊接热Resistance to Soldering Heat	JESD22-A106	Tsol= (260±5) °C, t=10s	3 次3 times	22	0/22
静电放电 ESD-HBM	JESD22-A114	Ta=25°C, HBM (2000V)	正反各 3 次 P&N 3 times	10	0/10
高温贮存High emperature Storage	JESD22-A103	Ta=125°C	1000h	22	0/22
低温贮存 Low Temperature Storage	JESD22-A119	Ta= -55°C	1000h	22	0/22
冷热冲击 Thermal Shock	JESD22-A104	-55°C(15min)↔ 125°C(15min)	循环 300 次 300 cycles	22	0/22
常温寿命试验 Lifespan Test	JESD22-A108	Ta=25°C, IF=50mA , Vcc=5V	1000h	22	0/22
高温寿命试验 DC Operating Life	JESD22-A108	Ta=110°C, IF=20mA , Vcc=5V	1000h	76	0/76
高温高湿偏压 High Temperature High Humidity bias Voltage	JESD22-A101	Ta =85°C , RH=85% IF=0mA , VCE=64V	1000h	22	0/22
高温偏压 High Temperature bias Voltage	JESD22-A108	Ta =110°C , IF=0mA , VCE=80V	1000h	22	0/22
高压蒸汽试验 High pressure steam test	JESD22-A102	P=15PSIG , 121°C, 100%RH	96h	22	0/22

◆ 回流焊温度曲线图 Solder Reflow Profile

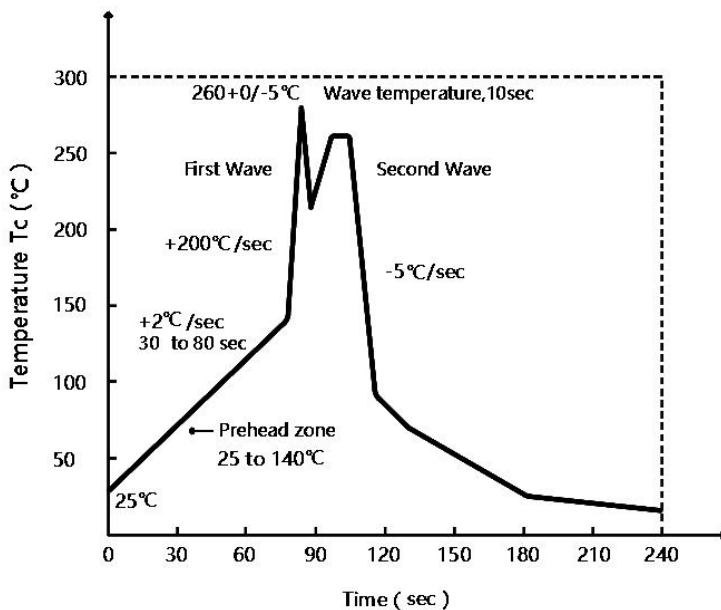


有铅制程 Lead Process



无铅制程 Lead Process

◆ 波峰焊温度曲线图 Wave Soldering Profile



◆ 手工烙铁焊接 Soldering with hand soldering iron

A. 手工烙铁焊仅用于产品返修或样品测试;

Hand soldering iron is only used for product rework or sample testing;

B. 手工烙铁焊要求: 温度 $350^{\circ}\text{C} \pm 5^{\circ}\text{C}$, 时间 $\leq 3\text{s}$ 。

Hand soldering iron requirements: Temperature: $350^{\circ}\text{C} \pm 5^{\circ}\text{C}$, within 3s.

◆ 注意 Attention

- 奥特半导体实施动态技术迭代机制，产品规格可能随工艺升级调整，最新技术参数以官网发布版本为准。

AOTE implements dynamic technical updates. Specifications are subject to change. Refer to the official website for the latest version.

- 用户需严格遵循本规格书限定的操作条件，因超范围使用（包括但不限于过载、高温、非兼容电路设计）导致的器件失效，不在质量保证范围内。

Users must strictly adhere to specified conditions. Failures caused by misuse (overload, high temperature, incompatible circuits) are excluded from warranty.

- 医疗设备、工业控制等关键场景应用前，需联系技术支持获取定制化验证方案。

Contact technical support for customized validation in critical applications (medical devices, industrial control).

- 本文档有效期至2025年12月31日，后续更新将通过官网公告推送。

This document is valid until Dec 31, 2025. Updates will be notified on the official website.

- 如需对技术参数或应用方案进行进一步确认，欢迎通过以下渠道获取官方支持：

For further clarification on technical specifications or application solutions, please contact us through official channels: